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## Fabrication and characterization of mid-infrared emission of Pr<sup>3+</sup> doped selenide chalcogenide glasses and fibres

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A series of Pr<sup>3+</sup>-doped selenide glasses was prepared by a melt-quenching method. The Pr<sup>3+</sup> doped fibre optic preform was fabricated using extrusion and was successfully drawn into a low optical loss, step-index fibre. Intense mid-infrared (2.8–5.5  $\mu\text{m}$ ) fluorescence spectra were achieved at different concentrations of Pr<sup>3+</sup> doped selenide glass with a pump of 2.0  $\mu\text{m}$ . A comparison of the emission spectra of bulk glass and the fibres is presented under 2.0  $\mu\text{m}$  wavelength excitation. The strongest emission was achieved due to the dispersion effect of Ga by forming bonds of Pr<sup>3+</sup>–Se–Ga. Based on the measured absorption spectra, the Judd–Ofelt parameters were calculated, discussed and compared with other host glasses. Given these properties, this system has the potential to be a good gain material for further development to realize both fibre lasers and amplified spontaneous emission fibre sources in the mid-infrared region.

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## Introduction

The mid-infrared (MIR) covers the important atmospheric window of 3–5  $\mu\text{m}$  and is one of the most intensively developing subjects in photonics at present. Besides, new wavelengths for laser machining and welding materials are of interest. For example, human tissue cutting and welding, neurosurgery, dermatology and bio-imaging are of international interest.<sup>1–4</sup> Mid-IR fibre laser machining and welding of polymers will be facilitated by resonance between the laser light frequency and the vibrational absorption of the polymer chemical bonding. To exploit the mid-IR region effectively requires the development of a raft of new active mid-infrared materials, including mid-IR fibre lasers.

Rare-earth ions are known to offer numerous transitions from 3 to 10  $\mu\text{m}$  for potential exploitation in a glass fibre laser format. Up to now, the longest wavelength of the fibre laser is 3.95  $\mu\text{m}$  obtained in a Ho<sup>3+</sup>-doped ZBLAN fibre with liquid nitrogen cooling.<sup>5</sup> But beyond 3  $\mu\text{m}$ , the multiphonon relaxation rates of fluoride glasses compete with the sharp-line luminescence. So other vitreous or crystalline materials with lower phonon energies must be sought as the host materials.

Chalcogenide glasses (ChG) have several properties that make them attractive as hosts for rare-earth ions.<sup>6–8</sup> The primary advantage for choosing a chalcogenide host is its smaller phonon energy as compared to ZBLAN ( $\sim 565\text{ cm}^{-1}$ ) and silicate

( $\sim 1100\text{ cm}^{-1}$ ) glass hosts. This smaller phonon energy, 400–450  $\text{cm}^{-1}$  for sulphide and 350  $\text{cm}^{-1}$  for selenide glass, results in a smaller multiphonon transition probability, thereby activating many mid-IR transitions for rare-earth ions which are normally quenched in hosts with larger phonon energies.<sup>9</sup> The high index and low phonon energy of the host ChG result in larger oscillator strengths and higher quantum efficiencies for RE ion transitions than in silica or fluoride glass.<sup>9</sup>

One promising selenium host glass is the Ge–As–Ga–Se (GAGS) glass system.<sup>10</sup> This host provides a low tendency to crystallize, higher mechanical properties and improved solubility of the RE-ions. The increased solubility of the RE-ions is due to the fact that the incorporation of Ga provides compensation for the negative charge of free Se<sup>2–</sup> ions by forming chemical bonds with RE-ions.<sup>11–15</sup>

A significant research effort has been put into studying the photoluminescence of lanthanide doped GAGS glasses and fibres. Cole *et al.*<sup>12</sup> (1999) investigated the mid-IR emission of Pr<sup>3+</sup> doped (200 ppmw) GAGS glasses and fibres. The emission spectrum was taken from one end of a fibre having a length of approximately 30 cm. Shiryayev *et al.*<sup>16</sup> (2014) provided a new vapour phase transport approach of metallic Ga transfer in a GaI<sub>3</sub> flow, developed to purify and add the batch of metallic gallium into the silica glass reactor for the GAGS glass synthesis. The content of residual impurities is: hydrogen 0.15 ppm, oxygen <1 ppm, and transition metals less than 0.1 ppm. Sójka *et al.*<sup>17</sup> (2014) fabricated and characterized Pr<sup>3+</sup> doped (500 ppmw) GAGS core/GAGS clad step-index fibre. It was found that the mid-IR emission  $^3\text{H}_5 \rightarrow ^3\text{H}_4$  efficiency was determined to be close to 100% based on J–O analysis. Hu *et al.*<sup>18</sup> (2015) computationally investigated cascaded amplification in a three-level mid-infrared

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(IR)  $\text{Pr}^{3+}$ -doped GAGS fibre amplifier. High gain and low noise are achieved simultaneously at 4.5  $\mu\text{m}$ . This shows that 45% of the pump power that is injected at 2  $\mu\text{m}$  can be shifted to 4.5  $\mu\text{m}$ . The authors set the  $\text{Pr}^{3+}$  ion density equal to  $2 \times 10^{19} \text{ cm}^{-3}$ , which corresponds to 0.1 wt% or 1000 ppmw  $\text{Pr}^{3+}$ -doped GAGS glass fibres. The equivalent atomic percentage of the  $\text{Pr}^{3+}$  is 0.055 mol%. However, the  $\text{Pr}^{3+}$  doping concentration of the reported GAGS fibre is less than 1000 ppmw. Therefore, we selected the GAGS glass as the host glass for investigating the effect of  $\text{Ga}^{3+}$  and  $\text{Pr}^{3+}$  dopant concentrations on luminescence.

In this paper, the successful fabrication of  $\text{Pr}^{3+}$ -doped  $\text{Ge}_{10}\text{As}_{24}\text{Ga}_4\text{Se}_{62}$  ( $\text{Pr}^{3+}$ :GAGS) glass and fibre with a doping concentration of  $\text{Pr}^{3+}$  up to 2050 ppmw (0.1 mol%) was reported.  $\text{Pr}^{3+}$  has a very wide MIR emission band from 3.0–5.5  $\mu\text{m}$  and was calculated to have a better amplification performance in a lower phonon energy host such as ChG. The optical properties of the  $\text{Pr}^{3+}$ -doped ChG were investigated. The emission and absorption spectra were recorded and analysed. The amorphous nature of the  $\text{Pr}^{3+}$ :GAGS glasses was studied by X-ray diffraction (XRD) and the J-O intensity parameters are presented. Besides, the MIR fluorescence properties of  $\text{Pr}^{3+}$ :GAGS glass and fibre pumped under 2  $\mu\text{m}$  lasers are compared and discussed.

## Experimental

### Glass preparation

A series glasses of  $\text{Ge}_{10}\text{As}_{24}\text{Ga}_x\text{Se}_{62}\text{Pr}_x$ , denoted as GAGS- $x$  ( $x = 0, 0.05, 0.1, 0.15, 0.2, 0.3, 0.4$ ), was prepared by a melt-quenching method. Ge (5N purity), As (5N purity), Ga (6N purity), Se (5N purity) and Pr (3N purity, batched inside a glove-box) were heated firstly in a silica glass ampoule under vacuum ( $10^{-3}$  Pa) to remove the volatile impurities, then the ampoule was sealed and melted for 18 hours at 750  $^{\circ}\text{C}$ , followed by quenching and annealing at the transition temperature.<sup>16</sup> After being cooled to the ambient slowly, the glasses were cut and polished for subsequent measurements.

### Fibre fabrication

The preforms were fabricated by a modified chalcogenide preform fabrication approach: isolated stacked extrusion. For details of the preparation process refer to the published work.<sup>19</sup> The extruded preforms were drawn into fibres of a few hundred micron diameters in the fibre drawing tower (SG Controls, UK).

The fibres were drawn to a diameter of 250  $\mu\text{m}$  at a rate of 0.5  $\text{m min}^{-1}$ , a temperature of 300  $^{\circ}\text{C}$  with a viscosity of about  $10^4$  to  $10^5$  Pa s. The 0.1 mol%  $\text{Pr}^{3+}$ -doped GAGS step-fibre had an outside diameter of 250  $\mu\text{m}$ . Numerical apertures (NA) of 0.19 were calculated for the fibre at a 4.5  $\mu\text{m}$  wavelength. Numerical apertures were calculated from refractive indices ( $n_{\text{core}} = 2.608$ ,  $n_{\text{clad}} = 2.601$ ) measured using an IR VASE mid-infrared Ellipsometer (J.A. Woollam Co., Inc.) at room temperature. During the drawing, the preform was protected in an inert gas atmosphere.

### Physical and optical measurements

The absorption spectra were collected using a PerkinElmer-Lambda 950UV/VIS/NIR spectrophotometer, in the range of

400–2500 nm. XRD patterns (X-ray diffraction) were collected under ambient conditions using a Bruker D2 X-ray diffractometer. MIR fluorescence spectra in the range of 2800–5500 nm were recorded by an InSb detector combined with a FLS980 fluorescence spectrometer at room temperature. A solid-state laser at 2.0  $\mu\text{m}$  was used as the excitation source. The fibre loss was measured by the cut-back method using a FTIR spectrometer (Thermo Scientific, Nicolet 5700, USA). The FTIR light was coupled into the fibre whose cross sections had been handled through the ZnSe lens with a NA of 0.67 and a focal length of 12.7 mm. The output terminal was connected to the liquid nitrogen cooled MCT detector. Adjusting the light path and measuring the output spectrum enabled the receiving light intensity of the detector to reach the maximum. We then cut off the fibre and measured the output spectrum again with the front end of the fibre fixed. To make the results comparable, a fixed configuration between the sample, laser, and detector was employed and carefully used. All the measurements were performed at room temperature.

## Results and discussion

### Effect of Ga on MIR

Fig. 1 shows the emission bands centred at 2.9  $\mu\text{m}$  and 3.3  $\mu\text{m}$  corresponding to the transitions of  $^1\text{G}_4 \rightarrow ^3\text{F}_3$  and  $^1\text{G}_4 \rightarrow ^3\text{F}_4$ . The broad emission band between 3.7  $\mu\text{m}$  and 5.5  $\mu\text{m}$  is attributed to the overlap of five transitions ( $^3\text{F}_4 \rightarrow ^3\text{F}_2/^3\text{H}_6$ ,  $^3\text{F}_3 \rightarrow ^3\text{H}_6$ ,  $^3\text{F}_2 \rightarrow ^3\text{H}_5$ ,  $^3\text{H}_6 \rightarrow ^3\text{H}_5$ ,  $^3\text{H}_5 \rightarrow ^3\text{H}_4$ ). The legends of GAS-Ga $_x$  in Fig. 1 are abbreviations for Ge-As-Se-Ga $_x$  ( $x = 1.0, 2.0, 3.0, 4.0, 5.0$  mol%, respectively). All the samples exhibited in Fig. 1 have the same concentration of  $\text{Pr}^{3+}$  (0.1 mol%) and different concentrations of  $\text{Ga}^{3+}$ . It is shown from the emission spectra excited by a 2000 nm LD laser that the MIR emission intensity was enhanced with the increase of  $\text{Ga}^{3+}$  ions from 1.0 to 4.0 mol%. Further increases of the  $\text{Ga}^{3+}$  concentration (5.0 mol%) decreased the fluorescence intensity.

In the past decade, several different approaches have been used to identify the chemical environment of REI ions in

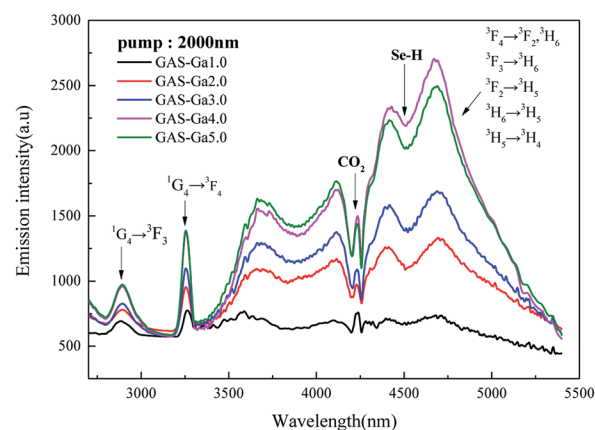


Fig. 1 Emission spectra of 0.1 mol%  $\text{Pr}^{3+}$  doped GAGS glasses with varying  $\text{Ga}^{3+}$  concentration (1.0, 2.0, 3.0, 4.0, 5.0 mol%, respectively) when pumped by a 2000 nm CW laser.



chalcogenide glasses and glass-ceramics. It is suggested that there are preferential spatial correlations between REI and the  $\text{GaS}_4$  tetrahedral even at low Ga-doping levels.<sup>20</sup> Furthermore, the phenomenon that Ga complexes the RE-ions by forming  $[\text{RE}^{3+}\text{-S-Ga}^{\text{III}}]$  type species has already been confirmed.<sup>21</sup> Therefore, according to the experience mentioned above and combined with the increase of the MIR intensity of  $\text{Pr}^{3+}$  ions shown in Fig. 1, it can be supposed that the introduction of Ga to the GeAsSe structure has dispersed  $\text{Pr}^{3+}$  ions in the glass.

### Absorption spectra and J–O analysis

The absorption spectra of 0.05–0.4 mol%  $\text{Pr}^{3+}:\text{Ge}_{10}\text{As}_{24}\text{Ga}_4\text{Se}_{62}$  glasses were measured in the wavelength region of 800–2250 nm (Fig. 2). The absorption bands with peaks located at 1005 nm, 1491 nm, 1605 nm and 2037 nm correspond to the transitions of the ground-state  $^3\text{H}_4$  to the excited levels  $^1\text{G}_4$ ,  $^3\text{F}_4$ , ( $^3\text{F}_3$ ,  $^3\text{F}_4$ ) and  $^3\text{F}_2$ , respectively. The cut-off edge at the short-wavelength of about 800 nm is due to the band gap absorption, which means the absorption band near 606 nm cannot be observed.<sup>22</sup>

The intensity parameters  $\Omega_t$  ( $t = 2, 4, 6$ ) are significant for the analysis of electron transitions within the 4f shell of RE-ions in solids.<sup>23–27</sup> The values of  $\Omega_2$  are related to the local environment of the RE-ions which is sensitive to the variation of the glass composition. The ratio of  $\Omega_4/\Omega_6$  is a radiative transition quality factor. As shown in Table 1, the calculated values of Judd–Ofelt (J–O) intensity parameters,  $\Omega_t$  ( $t = 2, 4, 6$ ), have an obvious mutation when the concentration of  $\text{Pr}^{3+}$  ion is up to 0.3 mol%. This is most likely due to crystallization, although the peaks of crystallization were not found in the XRD patterns (Fig. 3).

Though the  $\text{PrSe}_2$  crystalline phase peaks appeared as the concentration of the  $\text{Pr}^{3+}$  increased to 0.4 mol%, the crystal nucleus may be formed at 0.3 mol% and be too small to be detected by the XRD patterns. This indicated that the  $\text{Pr}^{3+}$  ions clustered to share the limited non-bridging selenium with the bonds changed from  $\text{Pr}^{3+}\text{-Se-Ga}$  to  $\text{Pr}^{3+}\text{-Se-Pr}^{3+}$  as the concentration of the  $\text{Pr}^{3+}$  increased to 0.3 mol%, which corresponds to the change in symmetry and local structure of  $\text{Pr}^{3+}$ .

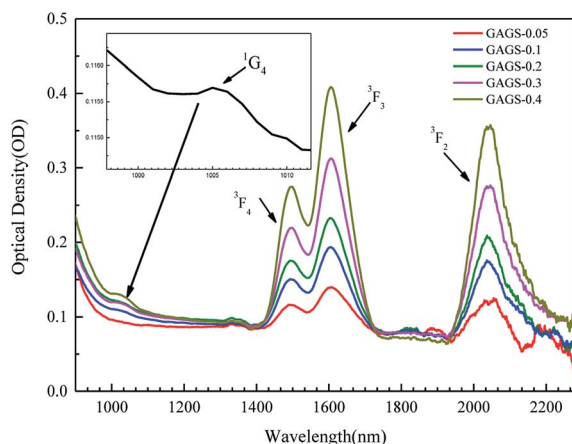


Fig. 2 Absorption spectra of 0.05–0.4 mol%  $\text{Pr}^{3+}:\text{GAGS}$  glasses in the range of 800–2250 nm obtained by UV/VIS/NIR spectrophotometer.

Table 1 The values of J–O intensity parameters  $\Omega_t$  ( $t = 2, 4, 6$ ), calculated from absorption spectra of  $\text{Ge}_{10}\text{As}_{24}\text{Ga}_4\text{Se}_{62}\text{Pr}_x$  ( $x = 0.05, 0.1, 0.2, 0.3, 0.4$ ) samples

Glass sample	$\Omega_2$ ( $\times 10^{-20} \text{ cm}^2$ )	$\Omega_4$ ( $\times 10^{-20} \text{ cm}^2$ )	$\Omega_6$ ( $\times 10^{-20} \text{ cm}^2$ )	$\Omega_4/\Omega_6$ ( $\times 10^{-20} \text{ cm}^2$ )
GAGS-0.05	2.01	17.74	8.65	2.05
GAGS-0.1	1.99	11.92	8.07	1.48
GAGS-0.2	1.99	10.34	7.47	1.38
GAGS-0.3	3.08	4.92	5.24	0.94
GAGS-0.4	3.24	4.56	5.01	0.91

ions. Thus, the J–O intensity parameters changed suddenly at a concentration of 0.3 mol%  $\text{Pr}^{3+}$ . The ratio of  $\Omega_4/\Omega_6$  decreased monotonously with the increase of  $\text{Pr}^{3+}$  concentration, shown in Table 2. It is obvious that the RE-ions of  $\text{Pr}^{3+}:\text{GAGS}$  glasses result in  $\text{Pr}^{3+}$  clusters as well as non-clustered  $\text{Pr}^{3+}$  ions. The parts with clustered  $\text{Pr}^{3+}$  ions had no or little contribution to the MIR emission. With the increase of  $\text{Pr}^{3+}$  concentration, the clusters of  $\text{Pr}^{3+}$  ions became more and more serious, so the radiative transition quality factor ( $\Omega_4/\Omega_6$ ) became smaller.

Table 2 shows the values of the oscillator strengths and J–O intensity parameters  $\Omega_t$ , calculated from our  $\text{Pr}^{3+}:\text{GAGS}$  sample and other hosts. Compared to other host glasses, the large refractive index and high degree of covalent bonding in the ChG results in oscillator strengths and radiative transition probabilities greater than in other host materials. Thus, the GAGS glass has the largest oscillator strengths,  $\Omega_2$  and  $\Omega_4/\Omega_6$ , as shown in Table 2. These properties indicate that the GAGS glass is a better host for MIR emission of  $\text{Pr}^{3+}$  ions.

### Amorphicity of $\text{Pr}^{3+}:\text{GAGS}$ glasses

Fig. 3 shows the X-ray diffraction patterns of 0–0.4 mol%  $\text{Pr}^{3+}:\text{GAGS}$  glasses. The absence of diffraction peaks in patterns of samples with concentrations of  $\text{Pr}^{3+}$  ions  $\leq 0.3$  mol% indicates an amorphous character (no crystallization). As the concentration of  $\text{Pr}^{3+}$  ions increased to 0.4 mol%, diffraction

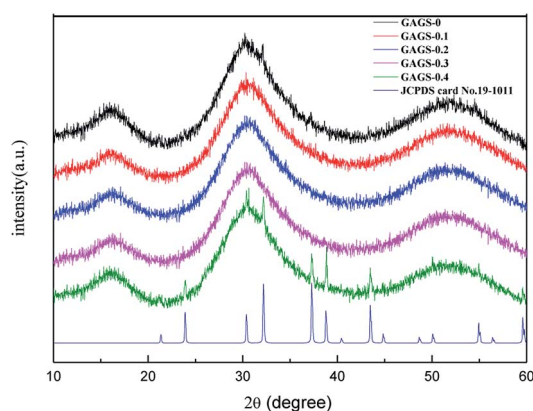


Fig. 3 XRD patterns of 0–0.4 mol%  $\text{Pr}^{3+}:\text{GAGS}$  glasses. The peaks on the "GAGS-0.4" curve are the diffraction peak of  $\text{PrSe}_2$  compared with JCPDS card no. 19–1011.



**Table 2** The oscillator strengths (fcal) and J–O intensity parameters,  $\Omega_t$  ( $t = 2, 4, 6$ ), of the 0.1 mol%  $\text{Pr}^{3+}$ :GAGS and other hosts

		GAGS	GAGS	Tellurite	Bismuthate	Oxyfluoride	ZBLAN
J–O intensity parameters	$\Omega_2$	2.01	9.05	0.264	1.30	0.13	0.94
$\Omega_4/(\times 10^{-20}, \text{cm}^2)$	$\Omega_4$	17.74	7.26	8.067	3.29	4.09	6.54
	$\Omega_6$	8.65	7.28	5.884	2.13	6.33	3.84
	$\Omega_4/\Omega_6$	2.05	1	1.37	1.54	0.65	1.7
Measured oscillator strengths	$^3\text{H}_4 \rightarrow ^1\text{G}_4$	1.004	—	0.35	0.63	0.18	3.14
fcal/ $(\times 10^{-6})$	$^3\text{F}_4$	12.170	—	3.88	5.29	11.98	4.05
	$^3\text{F}_3$	23.561	—	7.82	8.24	11.98	2.09
	$^3\text{F}_2$	12.836	—	3.63	1.63	3.39	0.99
Reference		Current work	17	28	29	30	31

peaks were observed which can be assigned to the  $\text{PrSe}_2$  crystalline phase (JCPDS card no. 19-1011). This reveals that no more RE-ions can be dissolved in the GAGS matrix. The higher concentration can affect the degree of symmetry of the  $\text{Pr}^{3+}$  local environment and result in clustering or inhomogeneous distribution. The devitrification of the heavy doping samples is due to the large coordination number of  $\text{Pr}^{3+}$  ions; with the increased  $\text{Pr}^{3+}$  ion concentration, there is not enough non-bridging selenium to separate them from each other. Then,  $\text{Pr}^{3+}$  ions will get together to share the non-bridging selenium or even to form clusters.

### Mid-IR luminescence

The mid-IR emission spectra ranging from 2.8  $\mu\text{m}$  to 5.5  $\mu\text{m}$  of the 0.05–0.4 mol%  $\text{Pr}^{3+}$ :GAGS glasses with the pump of a 2.0  $\mu\text{m}$  laser are shown in Fig. 4. As shown in Fig. 4, the emission bands centred at 2.9  $\mu\text{m}$  and 3.3  $\mu\text{m}$  correspond to the transitions of  $^1\text{G}_4 \rightarrow ^3\text{F}_3$  and  $^1\text{G}_4 \rightarrow ^3\text{F}_4$  with a pump of 2.0  $\mu\text{m}$ . This is because the excited state absorption (ESA) occurred in the transition of  $^3\text{F}_2 \rightarrow ^1\text{G}_4$  when pumped by a 2.0  $\mu\text{m}$  laser, as shown in Fig. 5.

The broad emission band between 3.7  $\mu\text{m}$  and 5.5  $\mu\text{m}$  that appears in Fig. 4 is attributed to the overlap of five transitions ( $^3\text{F}_4 \rightarrow ^3\text{F}_2/^3\text{H}_6$ ,  $^3\text{F}_3 \rightarrow ^3\text{H}_6$ ,  $^3\text{F}_2 \rightarrow ^3\text{H}_5$ ,  $^3\text{H}_6 \rightarrow ^3\text{H}_5$ ,  $^3\text{H}_5 \rightarrow ^3\text{H}_4$ ). The dips observed in both fluorescence spectra at 4.26 and 4.5

$\mu\text{m}$  can be attributed to ambient  $\text{CO}_2$  absorption in the optical path and impurities absorption of the Se–H bond, respectively.

The schematic energy-level diagram of  $\text{Pr}^{3+}$  ion for ESA and NIR transitions is shown in Fig. 5(a).<sup>32</sup> The NIR spectrum is shown in Fig. 5(b), which consists of the emission bands at 1.3 and 1.6  $\mu\text{m}$  corresponding to the  $^1\text{G}_4 \rightarrow ^3\text{H}_5$  and  $^3\text{F}_3 \rightarrow ^3\text{H}_4$  transitions, respectively. It can be seen that ESA exists in the transition of  $^3\text{F}_2 \rightarrow ^1\text{G}_4$  when excited at 2.0  $\mu\text{m}$ , which is in agreement with Fig. 4.

From both Fig. 4 and 5(b), it is clear that the 0.1 mol%  $\text{Pr}^{3+}$ -doped glass has the highest emission intensity and the intensity monotonously decreases for higher  $\text{Pr}^{3+}$  concentrations. At low  $\text{Pr}^{3+}$  concentrations, the dopants can be distributed uniformly by bonding to non-bridge selenium atoms forming the  $\text{Pr}^{3+}$ –Se–Ga bonds.

As the  $\text{Pr}^{3+}$  concentration increases, the  $\text{Pr}^{3+}$  ions must share the limited non-bridging selenium and then the clusters are formed through  $\text{Pr}^{3+}$ –Se– $\text{Pr}^{3+}$  bonding. Therefore, the local concentration of non-clustered  $\text{Pr}^{3+}$  become lower and the emission intensity become worse. Clustering facilitates the energy migration and fluorescence quenching by depopulating the excited states.

This process develops as the inter-ionic distance between the  $\text{Pr}^{3+}$  ions decreased in the lattice. In addition, the  $\text{PrSe}_2$  crystalline phase appeared in  $\text{Pr}^{3+}$ :GAGS glasses and made the Pr valence state change from trivalence to tetravalence, which decreased the emission intensity as well.

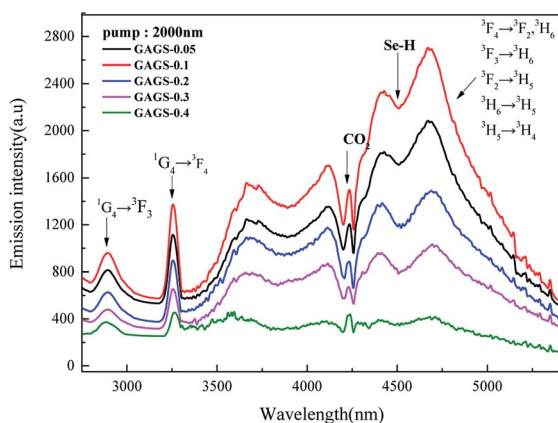
For laser applications, the values of the emission cross-section are of great interest. The effective line-width of the fluorescence band,  $\Delta\lambda_{\text{eff}}$ , is defined by:

$$\Delta\lambda_{\text{eff}} = \frac{\int I(\lambda) d\lambda}{I_{\text{max}}} \quad (1)$$

where  $\int I(\lambda) d\lambda$  represents the effective area of the peak and  $I_{\text{max}}$  is the maximum intensity at each fluorescence emission peak. The stimulated emission cross-section has been calculated using the flowing equation:

$$\sigma_{\text{emi}} = A_{\text{rad}} \left( \frac{\lambda_p^4}{8\pi c n^2 \Delta\lambda_{\text{eff}}} \right) \quad (2)$$

The effective line-width of the fluorescence band,  $\Delta\lambda_{\text{eff}}$ , and the stimulated emission cross-section  $\sigma_{\text{emi}}$  of a sample with 0.1



**Fig. 4** Emission spectra of  $\text{Pr}^{3+}$  doped GAGS glasses with varying  $\text{Pr}^{3+}$  concentrations (0.05, 0.1, 0.2, 0.3, 0.4 mol%, respectively) when pumped by a 2000 nm CW laser.





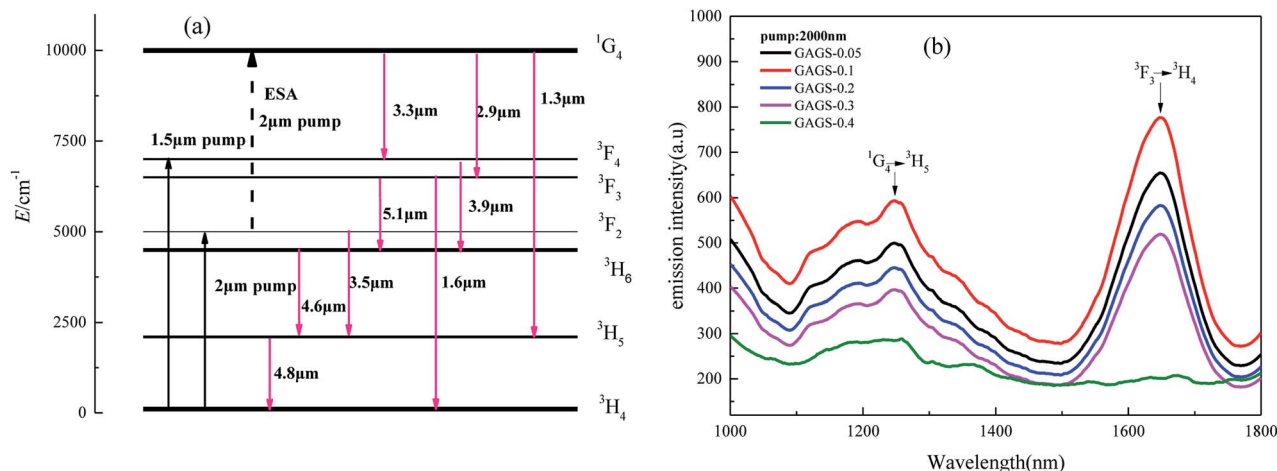


Fig. 5 Energy levels of  $\text{Pr}^{3+}$  with possible emission transitions shows the concept of ESA and NIR transitions in (a). The emission wavelengths were simply calculated from the energy gap between the 4f energy levels. (b) Shows the NIR emission spectra of the 0.05–0.4 mol%  $\text{Pr}^{3+}$ :GAGS glass pumped by a 2000 nm CW laser.

mol%  $\text{Pr}^{3+}$  are listed in Table 3. Examining Table 3, we see that the transitions are characterized by high cross-sections, long upper state lifetimes, and good branching ratios. These values indicate that many of the transitions are viable for MIR fibre lasers and amplifiers. The high cross-sections can be attributed to the enhancement of the local field factor due to the high index of chalcogenide glass.

### Fibre loss and MIR emission

The optical loss spectrum of the 250/125  $\mu\text{m}$  cladding diameter/core diameter, 0.1 mol%  $\text{Pr}^{3+}$  step-index glass fibre exhibited a lowest loss of 3.5 dB  $\text{m}^{-1}$  at a 6.9  $\mu\text{m}$  wavelength (Fig. 6). The absorption band at 2.9  $\mu\text{m}$  is assigned to O–H impurity vibrational absorption. The absorption band observed at 4.5  $\mu\text{m}$  is attributed to the ground state electronic absorption band  $^3\text{H}_5 \rightarrow ^3\text{H}_4$ , and also encompasses Se–H extrinsic impurity vibrational absorption. The absorption bands at 6.3  $\mu\text{m}$  and 7.8  $\mu\text{m}$  are assigned to  $\text{H}_2\text{O}$  and oxygen related (As–O and Ge–O) impurity vibrational absorption.

Fig. 7 shows the photoluminescence intensity of the 0.1 mol%  $\text{Pr}^{3+}$  for both bulk sample and fibre (80 mm) together in order to compare their band-shapes. For convenience, the emission spectra have been normalized. It can be seen that the fibre sample exhibits a greater proportion of its observed emission intensity at wavelengths  $>4800$  nm, compared to the

bulk sample. This is due to the long interaction length in optical fibres. For emission in the fibre, the shorter wavelength emission overlaps the absorption transition of  $^3\text{H}_5 \rightarrow ^3\text{H}_4$ . Therefore, the shorter wavelength emission is self-absorbed to be subsequently re-emitted at longer wavelengths.

It can be observed that the bandwidths of the luminescence in this selenide glass are much broader than those in sulphide glasses; this may due to the relatively higher stark splitting of  $\text{Pr}^{3+}$  ions generated by the larger oscillator strengths and asymmetry polyhedra in  $\text{Pr}^{3+}$ :GAGS glasses. Besides, the stimulated emission cross-section and branching ratio of the emission transition at 4.8  $\mu\text{m}$  is the largest. Furthermore, the radiative lifetime of the  $^3\text{H}_5$  state is much larger than that of the  $^3\text{H}_6$  state, so the transition of  $^3\text{H}_6 \rightarrow ^3\text{H}_5$  is a self-terminating transition. Meanwhile, the state of  $^3\text{H}_5$  can also be populated by reabsorption of the  $(^3\text{F}_2, ^3\text{H}_6) \rightarrow ^3\text{H}_5$  emission. Thanks to

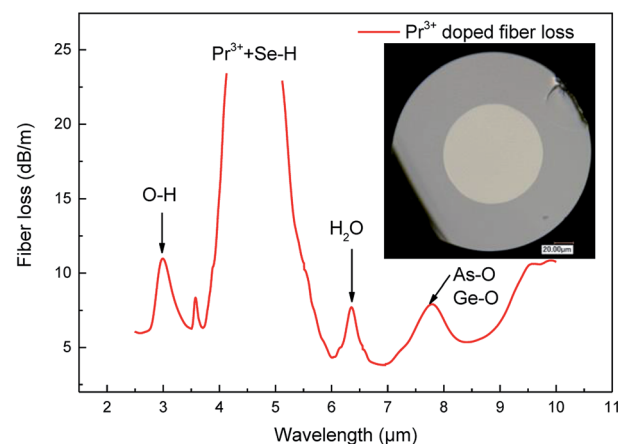


Fig. 6 Optical loss spectrum of the 0.1 mol%  $\text{Pr}^{3+}$ :GeAsGaSe core/GeAsGaSe clad. Step-index glass fibre drawn from the co-extruded core/clad preform. The inset is the optical photomicrograph of the fibre end face.

Table 3 The wavelength of fluorescence emission peak ( $\lambda_{\text{emi}}$ ), effective line-width of fluorescence band ( $\Delta\lambda_{\text{eff}}$ ), branching ratio ( $\beta$ ), radiative lifetimes ( $\tau$ ) and the stimulated emission cross-section ( $\sigma_{\text{emi}}$ ) of 0.1 mol%  $\text{Pr}^{3+}$  doped glass

Transition	$\lambda_{\text{emi}}$ ( $\mu\text{m}$ )	$\Delta\lambda_{\text{eff}}$ (nm)	$\beta\%$	$\tau$ (ms)	$\sigma_{\text{emi}} (\times 10^{-20} \text{ cm}^2)$
$^1\text{G}_4 \rightarrow ^3\text{F}_4$	2.90	120	19.82	5.95	0.46
$^3\text{H}_6 \rightarrow ^3\text{H}_5$	4.60	749	56.74	4.47	1.14
$^3\text{H}_5 \rightarrow ^3\text{H}_4$	4.80	752	100	10.74	1.30



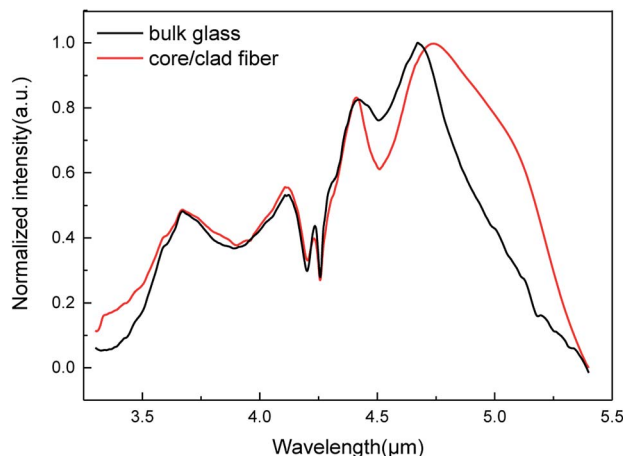


Fig. 7 Measured mid-IR emission spectrum of 0.1 mol%  $\text{Pr}^{3+}$  doped bulk glass GeAsGaSe sample and 0.1 mol%  $\text{Pr}^{3+}$ :GeAsGaSe core/GeAsGaSe clad step-index ChG fibre with preamplifier and 2000 nm CW laser excitation. Spectra are normalized at the peak wavelength.

these interactions between the excited states of  $\text{Pr}^{3+}$ , an easy population inversion can be anticipated for the broad emissions out of the  $^3\text{H}_5$  state when the gain medium has a long interaction length such as in optical fibres. Due to these parameters, the GAGS glasses with 0.1 mol%  $\text{Pr}^{3+}$  have a potential for application in lasers and amplifiers working at 4.8  $\mu\text{m}$ .

## Conclusions

A series of  $\text{Pr}^{3+}$ :GAGS glasses as potential gain materials for MIR laser devices were prepared and optically characterized. The 0.1 mol%  $\text{Pr}^{3+}$  doped step-index fibre has been successfully fabricated and its spectroscopic properties characterized. The J–O intensity parameters  $\Omega_t$  and oscillator strengths were calculated. Compared to other host glasses, the  $\text{Pr}^{3+}$ :GAGS glasses possessed the largest oscillator strengths,  $\Omega_2$  and  $\Omega_4/\Omega_6$ . The values of  $\Omega_t$  have a sudden jump when the concentration of  $\text{Pr}^{3+}$  ions increases to 0.3 mol%. This indicates that as the concentration of  $\text{Pr}^{3+}$  ions increases, the ratio of clustered  $\text{Pr}^{3+}$  ions to non-clustered  $\text{Pr}^{3+}$  ions becomes bigger and the emission intensity becomes weak. Mid-infrared (2.8–5.5  $\mu\text{m}$ ) fluorescence spectra of bulk glass and fibre were observed and compared under the pump of a 2.0  $\mu\text{m}$  laser. The highest emission intensity was obtained in GAGS-0.1 glass and the intensity substantially decreases for higher  $\text{Pr}^{3+}$  concentrations. The ESA occurred in the transition of  $^3\text{F}_2 \rightarrow ^1\text{G}_4$  when using an excitation wavelength of 2.0  $\mu\text{m}$  which contributed to the NIR-emissions of 1.3, 1.6, 2.9 and 3.3  $\mu\text{m}$ .

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